

GENERAL PURPOSE APPLICATION.  
HIGH VOLTAGE APPLICATION.

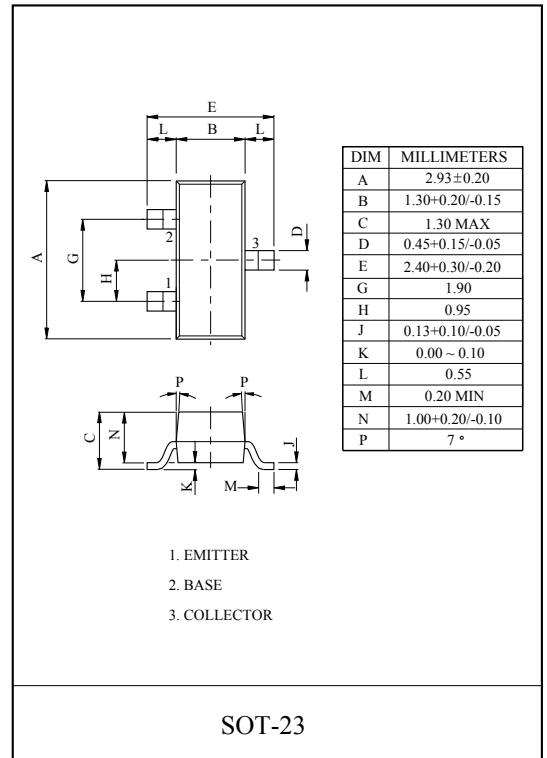
### FEATURES

- High Collector Breakdwon Voltage  
:  $V_{CBO} = -130V$ ,  $V_{CEO} = -120V$
- Low Leakage Current.  
:  $I_{CBO} = -100nA(\text{Max.}) @ V_{CB} = -100V$
- Low Saturation Voltage  
:  $V_{CE(\text{sat})} = -0.5V(\text{Max.}) @ I_C = -50mA, I_B = -5mA$
- Low Noise :  $NF = 8dB(\text{Max.})$

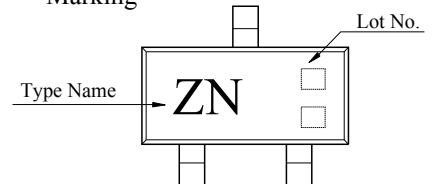
### MAXIMUM RATING (Ta=25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	$V_{CBO}$	-130	V
Collector-Emitter Voltage	$V_{CEO}$	-120	V
Emitter-Base Voltage	$V_{EBO}$	-5	V
Collector Current	$I_C$	-600	mA
Base Current	$I_B$	-100	mA
Collector Power Dissipation	$P_C^*$	350	mW
Junction Temperature	$T_j$	150	°C
Storage Temperature Range	$T_{stg}$	-55 ~ 150	°C

Note : \* Package Mounted On 99.5% Alumina  $10 \times 8 \times 0.6mm$ )



### Marking



# 2N5400S

## ELECTRICAL CHARACTERISTICS (Ta=25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	$I_{CBO}$	$V_{CB}=-100V, I_E=0$	-	-	-100	nA
		$V_{CB}=-100V, I_E=0, T_a=100^\circ C$	-	-	-100	$\mu A$
Emitter Cut-off Current	$I_{EBO}$	$V_{EB}=-3V, I_C=0$	-	-	-50	nA
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=-0.1mA, I_E=0$	-130	-	-	V
Collector-Emitter Breakdown Voltage *	$V_{(BR)CEO}$	$I_C=-1mA, I_B=0$	-120	-	-	V
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=-10\mu A, I_C=0$	-5	-	-	V
DC Current Gain *	$h_{FE(1)}$	$V_{CE}=-5V, I_C=-1mA$	30	-	-	
	$h_{FE(2)}$	$V_{CE}=-5V, I_C=-10mA$	40	-	180	
	$h_{FE(3)}$	$V_{CE}=-5V, I_C=-50mA$	40	-	-	
Collector-Emitter Saturation Voltage *	$V_{CE(sat)1}$	$I_C=-10mA, I_B=-1mA$	-	-	-0.2	V
	$V_{CE(sat)2}$	$I_C=-50mA, I_B=-5mA$	-	-	-0.5	
Base-Emitter Saturation Voltage *	$V_{BE(sat)1}$	$I_C=-10mA, I_B=-1mA$	-	-	-1.0	V
	$V_{BE(sat)2}$	$I_C=-50mA, I_B=-5mA$	-	-	-1.0	
Transition Frequency	$f_T$	$V_{CE}=-10V, I_C=-10mA, f=100MHz$	100	-	400	MHz
Collector Output Capacitance	$C_{ob}$	$V_{CB}=-10V, I_E=0, f=1MHz$	-	-	6	pF
Small-Signal Current Gain	$h_{fe}$	$V_{CE}=-10V, I_C=-1mA, f=1kHz$	30	-	200	
Noise Figure	NF	$V_{CE}=-5V, I_C=-250\mu A$ $R_g=1k\Omega, f=10Hz \sim 15.7kHz$	-	-	8	dB

\* Pulse Test : Pulse Width  $\leq 300\mu s$ , Duty Cycle  $\leq 2\%$ .

This datasheet has been download from:

[www.datasheetcatalog.com](http://www.datasheetcatalog.com)

Datasheets for electronics components.